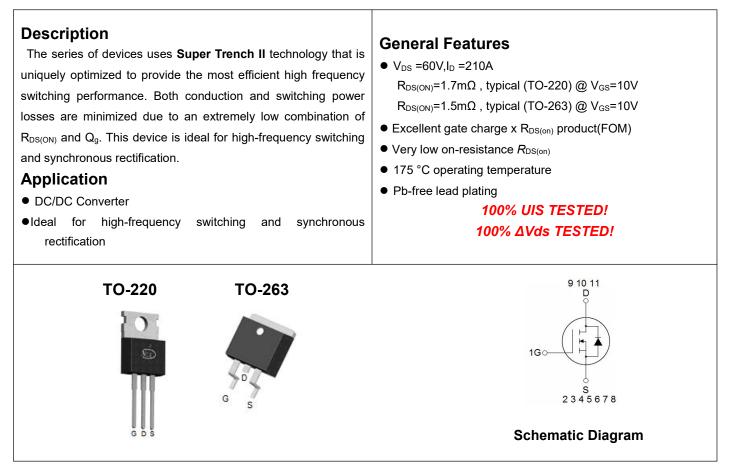


## NCE N-Channel Super Trench II Power MOSFET



## Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP018N60	NCEP018N60	TO-220	-	-	-
NCEP018N60D	NCEP018N60D	TO-263			

## Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (T <sub>c</sub> =25℃)	I <sub>D</sub> (Tc=25℃)	210	А
Drain Current-Continuous(Tc=100 °C)	I <sub>D</sub> ((Tc=100°C)	157	А
Pulsed Drain Current	I <sub>DM</sub>	840	А
Maximum Power Dissipation(Tc=25°C)	P <sub>D</sub> (T <sub>C</sub> =25℃)	255	W
Derating factor		1.7	W/°C
Single pulse avalanche energy <sup>(Note 1)</sup>	Eas	2332	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case	R <sub>eJC</sub>	0.59	°C/W	
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## Electrical Characteristics (T<sub>c</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	•	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics		· · ·					
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	60		-	V
Zero Gate Voltage Drain Current		I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current		I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics							
Gate Threshold Voltage		V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	TO-220	B	$V_{GS}$ =10V, $I_D$ =20A	-	1.7	2.0	mΩ
Drain-Source On-State Resistance	TO-263	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	1.5	2.0	mΩ
Forward Transconductance	•	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		150	-	S
Dynamic Characteristics							
Input Capacitance	Input Capacitance		V <sub>DS</sub> =30V,V <sub>GS</sub> =0V, F=1.0MHz	-	9433	-	PF
Output Capacitance Reverse Transfer Capacitance		Coss		-	1647	-	PF
		Crss		-	92.6	-	PF
Switching Characteristics (Note 2)							
Turn-on Delay Time		t <sub>d(on)</sub>		-	20	-	nS
Turn-on Rise Time		tr	V <sub>DD</sub> =30V,I <sub>D</sub> =20A	-	29	-	nS
Turn-Off Delay Time		t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_G$ =1.8 $\Omega$	-	50	-	nS
Turn-Off Fall Time		t <sub>f</sub>		-	25	-	nS
Total Gate Charge		Qg	V <sub>DS</sub> =30V,I <sub>D</sub> =20A, - V <sub>GS</sub> =10V	-	141	-	nC
Gate-Source Charge		Q <sub>gs</sub>		-	40		nC
Gate-Drain Charge		Q <sub>gd</sub>	VGS-10V -		26.7		nC
Drain-Source Diode Characteristi	cs	· · ·					
Diode Forward Voltage		V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =210A	-		1.2	V
Diode Forward Current		ls		-	-	210	А
Reverse Recovery Time		t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	80	-	nS
Reverse Recovery Charge		Qrr	di/dt = 100A/µs	-	175	-	nC

#### Notes:

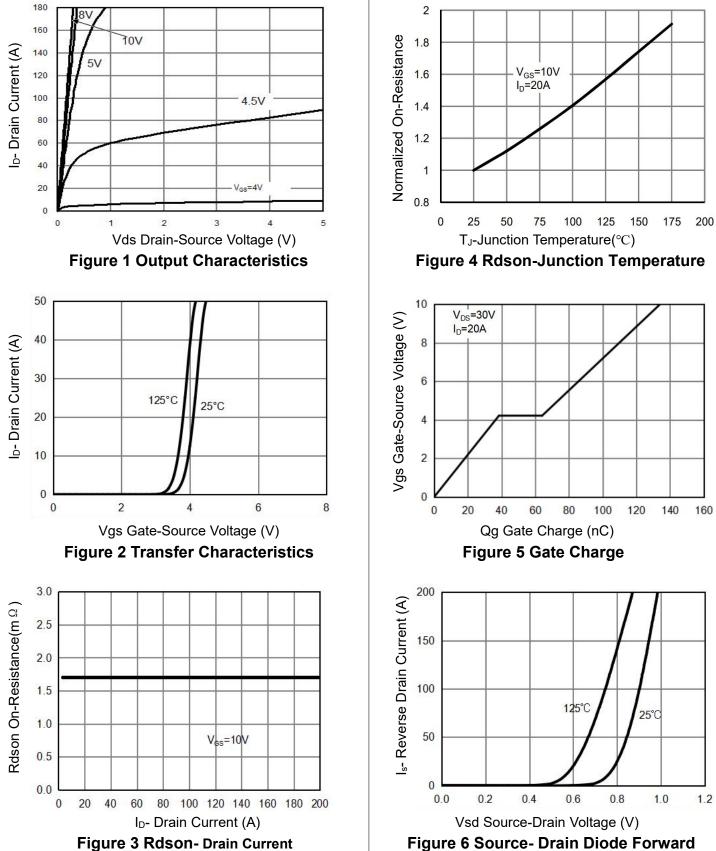
1. EAS condition : Tj=25  $^\circ \! \mathrm{C}, V_{DD}$ =30V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 

2. Guaranteed by design, not subject to production.

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heat sink, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.

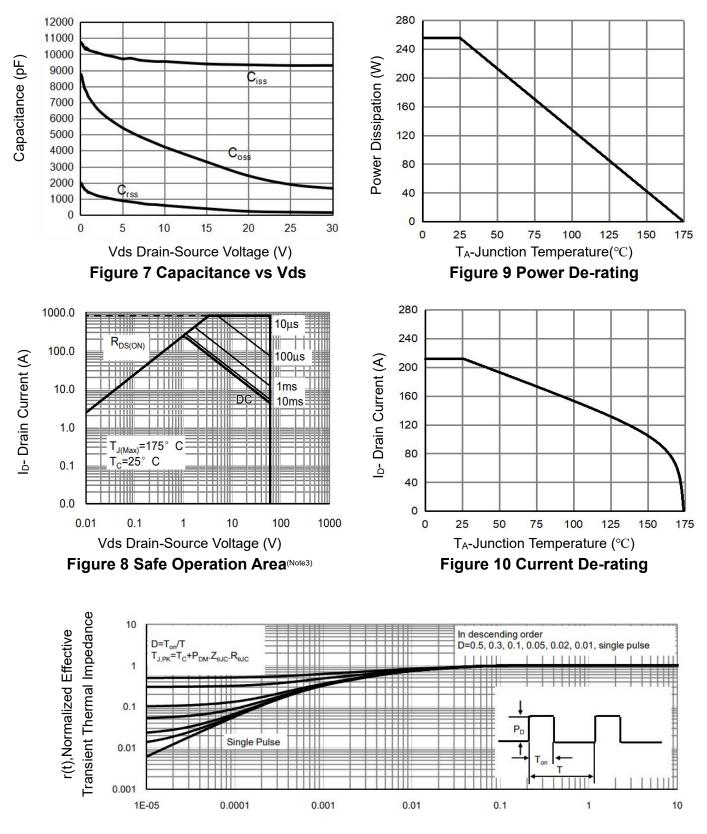


## **Typical Electrical and Thermal Characteristics**





# NCEP018N60,NCEP018N60D

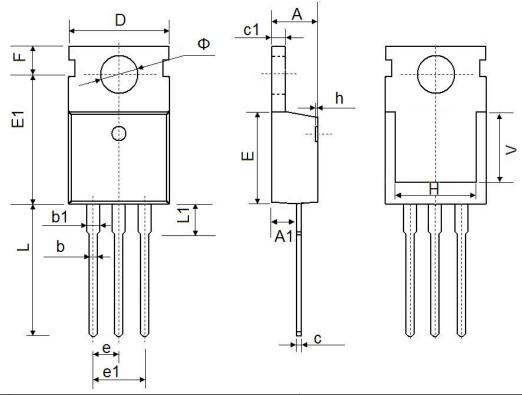


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



# TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches			
	Min.	Max.	Min.	Max.		
A	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
с	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.540	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	7.500	7.500 REF.		REF.		
Φ	3.400	3.800	0.134	0.150		



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